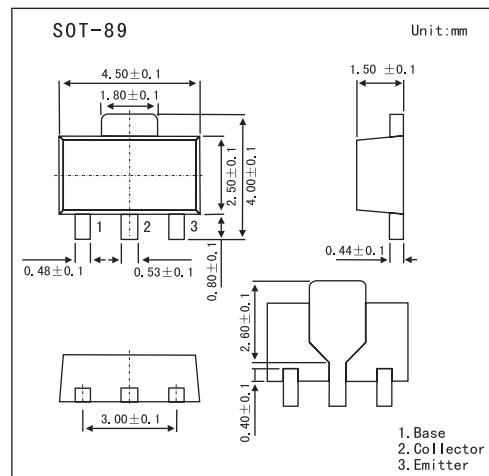


Silicon PNP Epitaxial Planar

2SB1572

■ Features

- Low $V_{CE(sat)}$: $V_{CE(sat)} \leq -0.4$ V
- Complementary to 2SD2403

■ Absolute Maximum Ratings $T_a = 25^\circ\text{C}$

| Parameter | Symbol | Rating | Unit |
|------------------------------|---------------------|-------------|------------------|
| Collector to Base Voltage | V_{CBO} | -80 | V |
| Collector to Emitter Voltage | V_{CEO} | -60 | V |
| Emitter to Base Voltage | V_{EBO} | -6 | V |
| Collector Current (DC) | $I_C(\text{DC})$ | -3 | A |
| Collector Current (pulse) * | $I_C(\text{Pulse})$ | -5 | A |
| Base Current (DC) | $I_B(\text{DC})$ | -0.2 | A |
| Base Current (pulse) * | $I_B(\text{Pulse})$ | -0.4 | A |
| Total Power Dissipation | P_T | 2 | W |
| Junction Temperature | T_j | 150 | $^\circ\text{C}$ |
| Storage temperature | T_{stg} | -55 to +150 | $^\circ\text{C}$ |

* $PW \leq 10$ ms, Duty Cycle $\leq 50\%$

2SB1572■ Electrical Characteristics $T_a = 25^\circ\text{C}$

| Parameter | Symbol | Testconditons | Min | Typ | Max | Unit |
|--------------------------------|----------------|---|-------|--------|-------|------|
| Collector Cut-off Current | I_{CBO} | $V_{CB} = -80 \text{ V}, I_E = 0$ | | | -100 | nA |
| Emitter Cut-off Current | I_{EBO} | $V_{EB} = -6.0 \text{ V}, I_C = 0$ | | | -100 | nA |
| DC Current Gain * | h_{FE1} | $V_{CE} = -2.0 \text{ V}, I_C = -0.1 \text{ A}$ | 80 | | | |
| | h_{FE2} | $V_{CE} = -2.0 \text{ V}, I_C = -1.0 \text{ A}$ | 100 | 200 | 400 | |
| Base to Emitter Voltage * | V_{BE} | $V_{CE} = -2.0 \text{ V}, I_C = -0.1 \text{ A}$ | -0.63 | -0.685 | -0.73 | V |
| Collector Saturation Voltage * | $V_{CE(sat)1}$ | $I_C = -2.0 \text{ A}, I_B = -0.1 \text{ A}$ | | -0.2 | -0.4 | V |
| Collector Saturation Voltage * | $V_{CE(sat)2}$ | $I_C = -3.0 \text{ A}, I_B = -0.15 \text{ A}$ | | -0.3 | -0.6 | V |
| Base Saturation Voltage * | $V_{BE(sat)}$ | $I_C = -2.0 \text{ A}, I_B = -0.1 \text{ A}$ | | -0.89 | -1.2 | V |
| Gain Bandwidth Product | f_T | $V_{CE} = -10 \text{ V}, I_E = 0.3 \text{ A}$ | 160 | | | MHz |
| Output Capacitance | C_{ob} | $V_{CB} = -10 \text{ V}, I_E = 0, f = 1.0 \text{ MHz}$ | 45 | | | pF |
| Turn-on Time | t_{on} | $I_C = -1.0 \text{ A}, V_{CC} = -10 \text{ V},$ $R_L = 5.0 \Omega, I_{B1} = -I_{B2} = -0.1 \text{ A},$ | 155 | | | ns |
| Storage Time | t_{stg} | | 510 | | | ns |
| Fall Time | t_f | | 35 | | | ns |

* Pulsed: $P_W \leq 350 \mu\text{s}$, Duty Cycle $\leq 2\%$.

■ hFE Classification

| Marking | HX | HY | HZ |
|---------|---------|---------|---------|
| hFE | 100~200 | 160~320 | 200~400 |